Form PTO-1449

INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary) MAY 1 5 2000 25

Attorney Docket No. A029 1080

Filing Date: 2/10/00

Serial No. 09/501,114

Applicant: Tzeng

GroupECEWED

1,0	W	1	9	لادرنالا

				U.	S. PATENT DOCUMENTS			MAY 19 2000	
Examiner Initials	Item	Document Number		Date	Name	Class	Subclass	CENTETING Date: 900 If Appropriate	
wn	AA	5,114,	745	05/19/92	Jones	427	113		
wn	AB	4,174,	380	11/13/79	Strong, et al.	423	446		
~W N_	AC	5,202,	156	04/13/93	Yamamoto et al.	427	135	1C	
ww	AD	5,270,	077	12/14/93	Knemeyer et al.	427	249	1700 1700	
₩ ~	AE	5,364,	423	11/15/94	Bigelow et al.	51	293		
W~	AF	5,382,	274	01/17/95	Yamamoto et al.	65	26	9 1A	
w~	AG	5,403,	619	040/4/95	Cuomo et al.	427	248	2381 L F	
w~	AH	5,451,	430	09/19/95	Anthony et al.	427	372.2	004	
w~	AI	5,468,	326	11/21/95	Cuomo et al.	156	345	<u> </u>	
ww	AJ	5,523,	121	06/04/96	Anthony et al.	427	249		
w~	AK	5,480,	686	01/02/96	Rudder et al	4:27	5:62		
				FORE	EIGN PATENT DOCUMENTS				
	Docum		Date	Country	Class	Subclass	Translation		
		Numbe	er					Yes No	
	AL								
w~		AM _.	High Performance Police	hing Techni	ENTS (Including Author, Title, Date, Pertiner ques for DVD Diamond; Final Report (Phase I) S or period 9/93 – 12/94, Y. Tommy Tzeng – Princ	Submitted to Nav	al Air Warfare C , Auburn Univers	enter Under	
w~		AN	Rapid Polishing of Thick Polycrystalline "White" CVD Diamond by Liquid Metal Films, Article, Department of Electrical Engineering, Auburn University, Y. Tzen, J. Wei, c. Cutshaw, and T. Chein						
Ww		AO	Polishing of CVD Diamond Film, Article Elsevier Science Publishers B.V., 1991, Hitoshi Tokura and Masanori Yoshikawa, Faculty of Engineering, Tokyo Institute of Technology						
ww		AP	Microwave CVD of Dia Research Society Symp	amond Using D. Proc. Vol.	g Methanol-Rare Gas Mixtures, M. Buck, T.M. C 162 (1990)	Chuang, J.H. Kau	fman and H. Seki	; Materials	
° ~~	-	AQ	Applications of Diamond Films and Related Materials, Y. Tzeng, M. Yoshikawa, M. Murakawa and A. Feldman; Materials Sicence Monographs, 73 (1991)						
ww		AR	Synthesis of Diamond in High Power-Density Microwave Methane/Hydrogen/Oxygen plasmas at Elevated Substrate Temperatures, T. Chein, J. Wei, and Y. Tzeng, Diamond and Related Materials 8, pp. 1686 - 1696 (1999)						
wn	•	AS	CVD Diamond Grown by Microwave Plasma in Mixtures of Acetone/Oxygen and Acetone/Carbon Dioxide, T. Chein and Y. Tzeng- Diamond and Related Materials 8, pp. 1393 – 1401 (1999)						
ww	,	AT	Toward a General Cond Materials 1, pp. 1 – 12		ond Chemical Vapour Deposition, P. Bachmann,	, D. Leers, and H	. Lydtin, Diamon	d and Related	

wn	AU	Diamond Synthesis b. the Microwave Plasma CVD Method Using a Mixture of Caroon Monoxide and Hydrogen Gas, T. Ito, A. Masuda, Y. Eto, K. Ito, and K. Nishimoto, Science and Technology of New Diamond, pp. 107 – 109 (1990)
wn	AV	Diamond Synthesis from Methane – Hydrogen – Water Mixed Gas Using a Microwave Plasma, Y. Saito, K. Sato, K. Tanaka, K. Fujita and S. Matuda, Hjournal of Materials Science, 23, 842 – 846 (1988)
ww	AW	Effects of Oxygen on CVD Diamond Synthesis, T. Kawato and K. Kondo, Japanese Journal of Applied Physics, pp. 1429 – 1432 (1987)

* EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.

EXAMINER'S SIGNATURE:

DATE CONSIDERED:

W

Jun /

7/23/01

Patent and Trademark Office; U. S. DEPARTMENT OF COMMERCE



RECEIVED TOWN BOWN

RECEIVED
RECEIVED
RECEIVED